

**COS/MUS
INTEGRATED
CIRCUIT**

7929225 S G S SEMICONDUCTOR CORP

BCD RATE MULTIPLIER

- CASCADABLE IN MULTIPLES OF 4-BITS
- SET TO 9 INPUT AND 9 DETECT OUTPUT
- QUIESCENT CURRENT SPECIFIED TO 20V FOR HCC DEVICE
- STANDARDIZED SYMMETRICAL OUTPUT CHARACTERISTICS
- 5V, 10V, AND 15V PARAMETRIC RATINGS
- INPUT CURRENT OF 100 nA AT 18V AND 25°C FOR HCC DEVICE
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC TENTATIVE STANDARD No. 13A, "STANDARD SPECIFICATIONS FOR DESCRIPTION OF "B" SERIES CMOS DEVICES"

The **HCC 4527B** (extended temperature range) and **HCF 4527B** (intermediate temperature range) are monolithic integrated circuit, available in 16-lead dual in-line plastic or ceramic package, and ceramic flat package.

The **HCC/HCF 4527** is a low-power 4-bit digital rate multiplier that provides an output-pulse rate which is the clock-input-pulse rate multiplied by 1/10 times the BCD input. For example, when the BCD input is 8, there will be 8 output pulses for every 10 input pulses. This device may be used to perform arithmetic operations (add, subtract, divide, raise to a power), solve algebraic and differential equations, generate natural logarithms and trigonometric functions, A/D and D/A conversion, and frequency division.

ABSOLUTE MAXIMUM RATINGS

V_{DD}^*	Supply voltage: HCC types HCF types	-0.5 to 20 -0.5 to 18	V V
V_i	Input voltage	-0.5 to $V_{DD} + 0.5$	V
I_i	DC input current (any one input)	± 10	mA
P_{tot}	Total power dissipation (per package)	200	mW
	Dissipation per output transistor for T_{op} = full package-temperature range	100	mW
T_{op}	Operating temperature: HCC types HCF types	-55 to 125 -40 to 85	°C °C
T_{stg}	Storage temperature	-65 to 150	°C

* All voltage values are referred to V_{SS} pin voltage

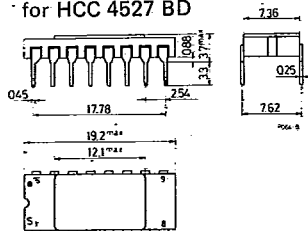
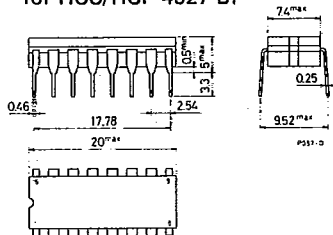
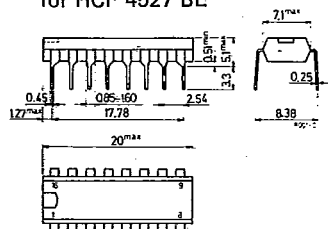
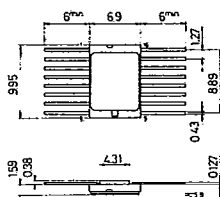
ORDERING NUMBERS:

HCC 4527 BD for dual in-line ceramic package
 HCC 4527 BF for dual in-line ceramic package, frit seal
 HCC 4527 BK for ceramic flat package
 HCF 4527 BE for dual in-line plastic package
 HCF 4527 BF for dual in-line ceramic package, frit seal

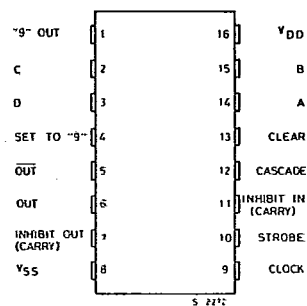
HCC/HCF 4527B

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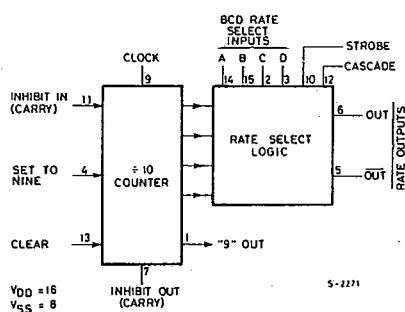
MECHANICAL DATA(dimensions in mm)

Dual in-line ceramic package
for HCC 4527 BDDual in-line ceramic package
for HCC/HCF 4527 BFDual in-line plastic package
for HCF 4527 BECeramic flat package
for HCC 4527 BK

CONNECTION DIAGRAM



FUNCTIONAL DIAGRAM



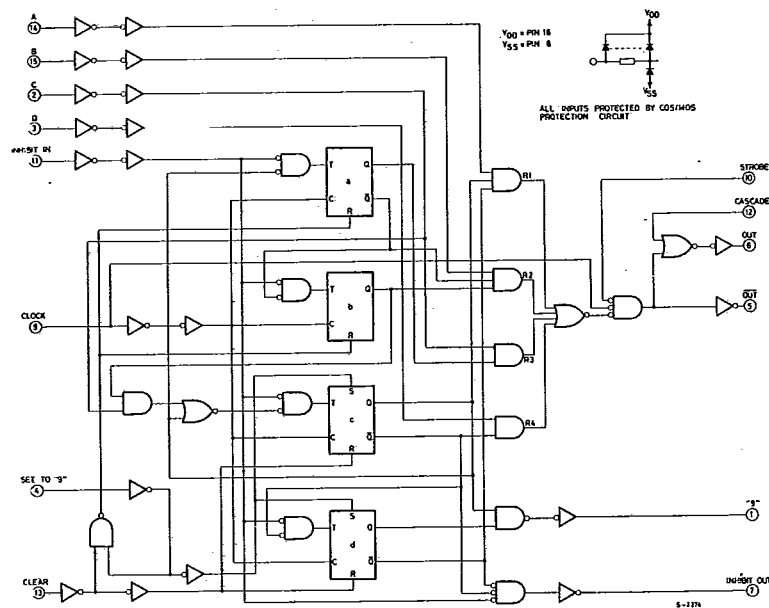
RECOMMENDED OPERATING CONDITIONS

V_{DD}	Supply voltage: HCC types	3 to 18	V
	HCF types	3 to 15	V
V_I	Input voltage	0 to V_{DD}	V
T_{op}	Operating temperature: HCC types	-55 to 125	°C
	HCF types	-40 to 85	°C



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LOGIC DIAGRAM



TRUTH TABLE

INPUTS										OUTPUTS			
Number of Pulses or Input Logic Level (0 = Low; 1 = High; X = Don't Care)										Number of Pulses or Output Logic Level (L = Low; H = High)			
D	C	B	A	CLK	INH IN	STR	CAS	CLR	SET	OUT	OUT	INH OUT	"9" OUT
0	0	0	0	10	0	0	0	0	0	L	H	1	1
0	0	0	1	10	0	0	0	0	0	1	1	1	1
0	0	1	0	10	0	0	0	0	0	2	2	1	1
0	0	1	1	10	0	0	0	0	0	3	3	1	1
0	1	0	0	10	0	0	0	0	0	4	4	1	1
0	1	0	1	10	0	0	0	0	0	5	5	1	1
0	1	1	0	10	0	0	0	0	0	6	6	1	1
0	1	1	1	10	0	0	0	0	0	7	7	1	1
1	0	0	0	10	0	0	0	0	0	8	8	1	1
1	0	0	1	10	0	0	0	0	0	9	9	1	1
1	0	1	0	10	0	0	0	0	0	8	8	1	1
1	0	1	1	10	0	0	0	0	0	9	9	1	1
1	1	0	0	10	0	0	0	0	0	8	8	1	1
1	1	0	1	10	0	0	0	0	0	9	9	1	1
1	1	1	0	10	0	0	0	0	0	8	8	1	1
1	1	1	1	10	0	0	0	0	0	9	9	1	1
X	X	X	X	10	1	0	0	0	0	▲	▲	H	▲
X	X	X	X	10	0	1	0	0	0	L	H	1	1
X	X	X	X	10	0	0	1	0	0	H	●	1	1
1	X	X	X	10	0	0	0	1	0	10	10	H	L
0	X	X	X	10	0	0	0	1	0	L	H	H	L
X	X	X	X	10	0	0	0	0	1	L	H	L	H

● Output same as the first 16 lines of this truth table (depending on values of A, B, C, D).

▲ Depends on internal state of counter.



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STATIC ELECTRICAL CHARACTERISTICS (over recommended operating conditions)

Parameter			Test conditions				Values						Unit	
			V _I (V)	V _O (V)	I _O (μA)	V _{DD} (V)	T _{Low} *		25°C			T _{High} *		
							Min.	Max.	Min.	Typ.	Max.	Min.		Max.
I _L	Quiescent current	HCC types	0/ 5			5		5		0.04	5		150	μA
			0/10			10		10		0.04	10		300	
			0/15			15		20		0.04	20		600	
			0/20			20		100		0.08	100		3000	
		HCF types	0/ 5			5		20		0.04	20		150	
			0/10			10		40		0.04	40		300	
		0/15			15		80		0.04	80		600		
V _{OH}	Output high voltage	0/ 5		< 1	5	4.95		4.95			4.95		V	
		0/10		< 1	10	9.95		9.95			9.95			
		0/15		< 1	15	14.95		14.95			14.95			
V _{OL}	Output low voltage	5/0		< 1	5		0.05			0.05		0.05	V	
		10/0		< 1	10		0.05			0.05		0.05		
		15/0		< 1	15		0.05			0.05		0.05		
V _{IH}	Input high voltage		0.5/4.5	< 1	5	3.5		3.5			3.5		V	
			1/9	< 1	10	7		7			7			
			1.5/13.5	< 1	15	11		11			11			
V _{IL}	Input low voltage		4.5/0.5	< 1	5		1.5			1.5		1.5	V	
			9/1	< 1	10		3			3		3		
			13.5/1.5	< 1	15		4			4		4		
I _{OH}	Output drive current	HCC types	0/ 5	2.5		5	-2		-1.6	-3.2		-1.15		mA
			0/ 5	4.6		5	-0.64		-0.51	-1		-0.36		
			0/10	9.5		10	-1.6		-1.3	-2.6		-0.9		
			0/15	13.5		15	-4.2		-3.4	-6.8		-2.4		
		HCF types	0/ 5	2.5		5	-1.53		-1.36	-3.2		-1.1		
			0/ 5	4.6		5	-0.52		-0.44	-1		-0.36		
			0/10	9.5		10	-1.3		-1.1	-2.6		-0.9		
			0/15	13.5		15	-3.6		-3.0	-6.8		-2.4		
I _{OL}	Output sink current	HCC types	0/ 5	0.4		5	0.64		0.51	1		0.36	mA	
			0/10	0.5		10	1.6		1.3	2.6		0.9		
			0/15	1.5		15	4.2		3.4	6.8		2.4		
		HCF types	0/ 5	0.4		5	0.52		0.44	1		0.36		
			0/10	0.5		10	1.3		1.1	2.6		0.9		
			0/15	1.5		15	3.6		3.0	6.8		2.4		
I _{IH} , I _{IL}	Input leakage current	HCC types	0/18	Any input	18		±0.1		±10 ⁻⁵	±0.1		± 1	μA	
		HCF types	0/15		15		±0.3		±10 ⁻⁵	±0.3		± 1		
C _I	Input capacitance			Any input					5	7.5			pF	

* T_{Low} = - 55°C for HCC device: -40°C for HCF device.* T_{High} = +125°C for HCC device: +85°C for HCF device.The Noise Margin for both "1" and "0" level is: 1V min. with V_{DD}= 5V2V min. with V_{DD}= 10V2.5V min. with V_{DD}= 15V

DYNAMIC ELECTRICAL CHARACTERISTICS ($T_{amb} = 25^{\circ}\text{C}$, $C_L = 50 \text{ pF}$, $R_L = 200 \text{ k}\Omega$, typical temperature coefficient for all V_{DD} values is $0.3\%/^{\circ}\text{C}$, all input rise and fall times = 20 ns)

Parameter		Test conditions	Values			Unit	
			V _{DD} (V)	Min.	Typ.		Max.
t _{PHL} , t _{PLH} Propagation delay time	Clock to out		5		110	220	ns
			10		55	110	
			15		45	90	
	Clock or strobe to out		5		150	300	ns
			10		75	150	
			15		60	120	
	Clock to inhibit out high level to low level		5		320	640	ns
			10		145	290	
			15		100	200	
	Low level to high level		5		250	500	ns
			10		100	200	
			15		75	150	
Clear to out		5		380	760	ns	
		10		175	350		
		15		130	260		
Clock to "9" or "1" out		5		300	600	ns	
		10		125	250		
		15		90	180		
Cascade to out		5		90	180	ns	
		10		45	90		
		15		35	70		
Inhibit input to inhibit out		5		130	260	ns	
		10		60	120		
		15		45	90		
Set to out		5		330	660	ns	
		10		150	300		
		15		110	220		
t _{THL} , t _{TLH} Transition time		5		100	200	ns	
		10		50	100		
		15		40	80		
f _{CL} Maximum clock frequency		5	1.2	2.4		MHz	
		10	2.5	5			
		15	3.5	7			
t _w Clock pulse width		5	330	165		ns	
		10	170	85			
		15	100	50			
t _r , t _f Clock rise or fall time		5			15	μs	
		10			15		
		15			15		
t _w Set or clear pulse width		5	160	80		ns	
		10	90	45			
		15	60	30			

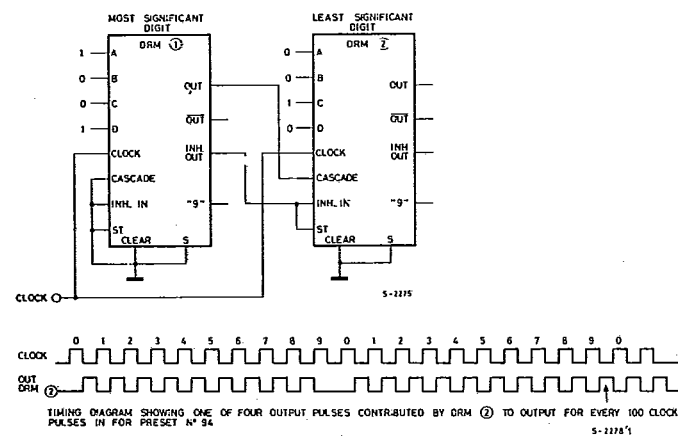
DYNAMIC ELECTRICAL CHARACTERISTICS (continued)

Parameter	Test conditions	Values			Unit
		V _{DD} (V)	Min.	Typ.	Max.
t _{setup} Inhibit input setup time		5	100	50	ns
		10	40	20	
		15	20	10	
t _R Inhibit input removal time		5	240	120	ns
		10	130	65	
		15	110	55	
t _R Set removal time		5	150	75	ns
		10	80	40	
		15	50	25	
t _R Clear removal time		5	60	30	ns
		10	40	20	
		15	30	15	

APPLICATIONS NOTE

For fractional multipliers with more than one digit, HCC/HCF 4527 devices may be cascaded in two different modes: the Add mode and the Multiply mode. See figs. 1 and 3.

Fig. 1 - Two HCC/HCF 4527B cascaded in the "Add" mode with a preset number



When two units are cascaded in Add mode and programmed to 9 and 4 respectively, the more significant unit will have 9 output pulses for every 10 input pulses and the other unit will have 4 output pulses for every 100 input pulses for a total of $\frac{9}{10} + \frac{4}{100} = \frac{94}{100}$.

The Addition of two variables, A and B is instead obtained with this application:

Fig. 2 - Addition of two variables, A and B

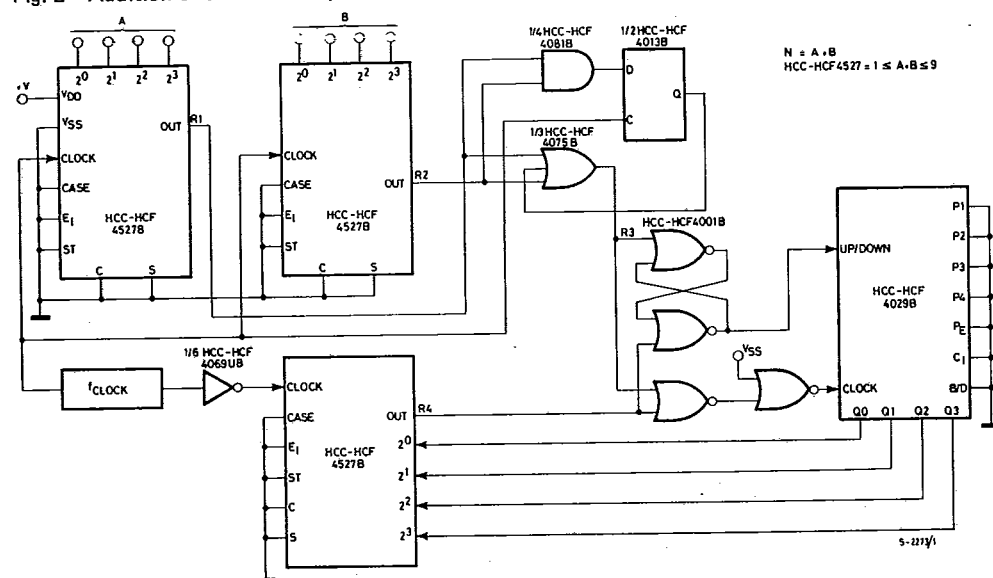
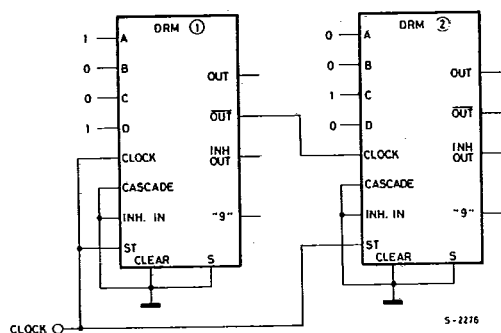


Fig. 3 - Two HCC/HCF 4527B cascaded in the "Multiply" mode with a preset number



In the Multiply mode, the fraction programmed into the first rate multiplier is multiplied by the fraction programmed into the second one: $I_f \quad N_1 = 9$ and $N_2 = 4$

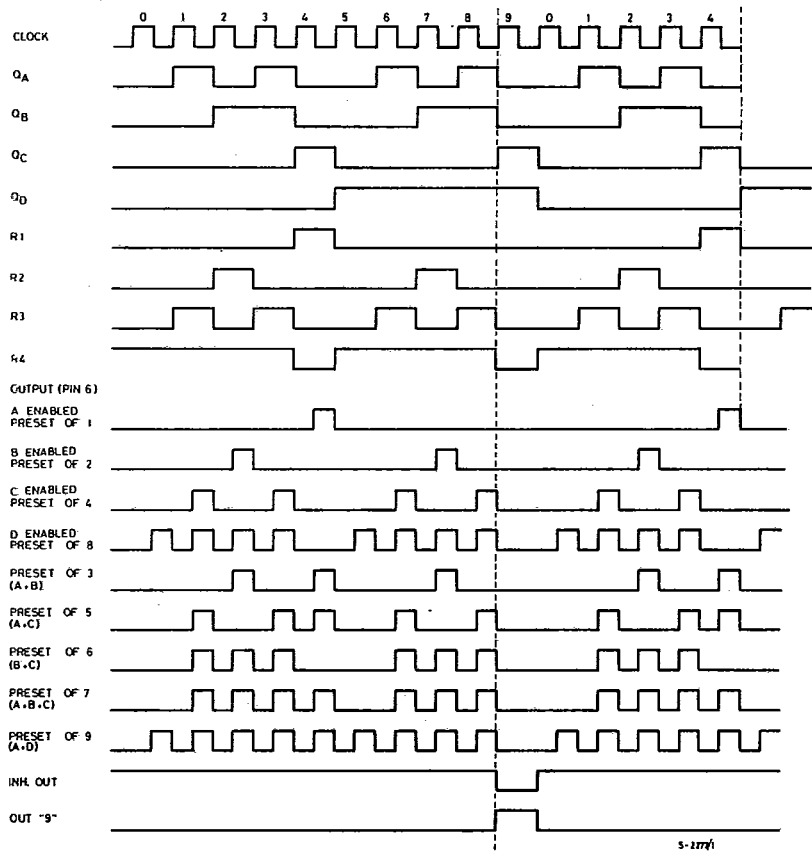
$$f_{out2} = \left(\frac{4}{10}\right) \cdot f_{out1} \qquad f_{out1} = \frac{9}{10} f_{clock} \qquad f_{out2} = \frac{4}{10} \times \left(\frac{9}{10} f_{clock}\right) = \frac{36}{100} f_{clock}$$

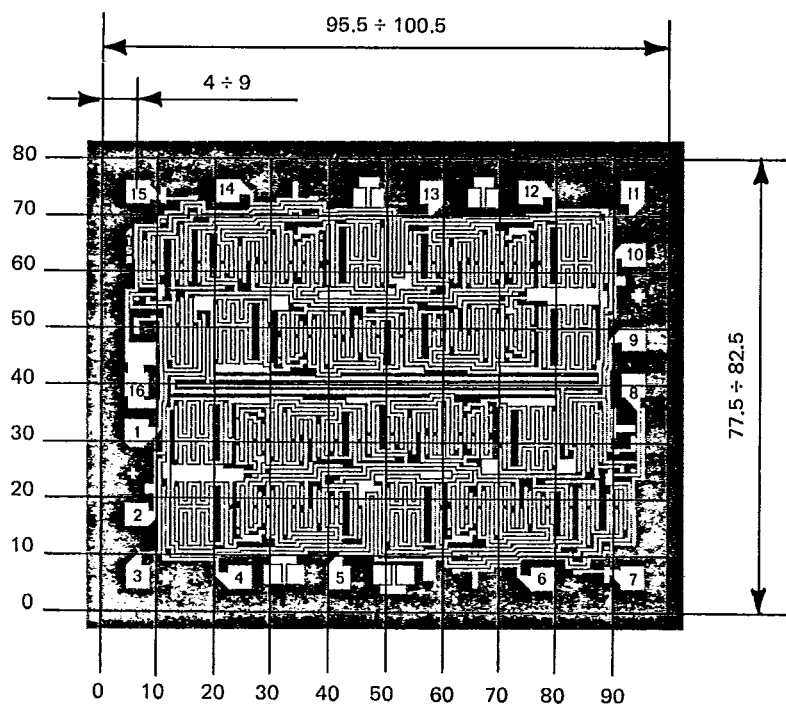
There fore 36 output pulses for every 100 clock input pulses.

HCC/HCF 4527B

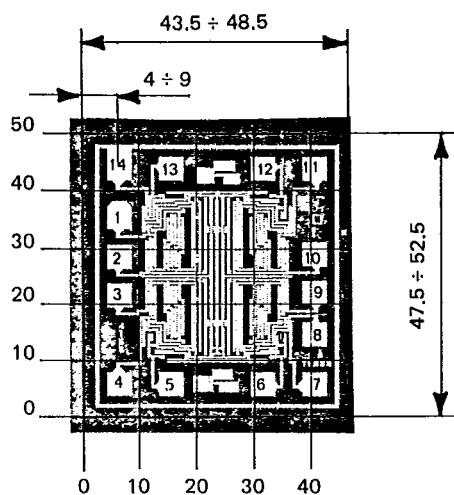
APPLICATIONS NOTE (continued)

Fig. 4 - Timing diagram (see Logic Diagram)





4015B



4016B